The author is thankful to Prof. B. N. Srivastava, D.Sc., F.N.I., for his keen interest in the problem.

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ELECTRIC AND THERMOELECTRIC PROPERTIES OF NATURAL CRYSTALS OF HEMATITE

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(Received December 20, 1968)

The electrical conductivity (σ) and Seebeck voltage (with respect to Pt) (θ) of crystals of a sample of naturally occuring hematite (Brazil : Fe₂O₃ 95.5%, FeO .5%, SiO₂ 1.7%, TiO₂ 1.9%, MgO .2%, Al₂O₃ .13%, S .1%, H₂O .15%) were measured both along the trigonal axis and the basal plane between 100°K and 1000°K for fresh as well as heat treated samples (figures. 1 and 2). These were found to be *n*-type semiconductors and the conductivity can be represented by

 $\sigma = \sigma_0 \exp{-\Delta E/kT}$

where the symbols have their usual meaning. The values for ΔE and σ_0 are given in table 1.

Crystal samples	Fresh (a)			Heat treated (b)		
	$\Delta E \text{ in } \\ e.v.$	σ_0 $\Omega^{-1} \text{ cm}^{-1}$	Temp. range °K	∆ <i>E</i> in e.v.	σ_0 Ω^{-1} cm $^{-1}$	Tomp. rango °K
1) In plane	0.079 0.109	1.38 11.5	<220 220 <t<585< td=""><td>0.066 0.102 0.190</td><td>0.026 0.087 1.20</td><td><270 270<t<440 440<t<780< td=""></t<780<></t<440 </td></t<585<>	0.066 0.102 0.190	0.026 0.087 1.20	<270 270 <t<440 440<t<780< td=""></t<780<></t<440
2) "	0.066 0.095	0.76 4.80	<200 200 <t<450< td=""><td>0.066 0.198</td><td>0.026 8.30</td><td><270 270<t<735< td=""></t<735<></td></t<450<>	0.066 0.198	0.026 8.30	<270 270 <t<735< td=""></t<735<>
3) Along c-axis	0.07 <u>4</u> 0.189	0.145 11.5	<205 205 <t<640< td=""><td>0.080 0.223</td><td>0.0105</td><td><310 310 < T < 700 <260</td></t<640<>	0.080 0.223	0.0105	<310 310 < T < 700 <260
4) ,,	0.090 0.238 0.439	0.251 14.1 16 3	<210 210 <t<440 440<t<625< td=""><td>0.095 0.179 0.343</td><td>1.14 83</td><td>260<t<400 400<t<650< td=""></t<650<></t<400 </td></t<625<></t<440 	0.095 0.179 0. 343	1.14 83	260 <t<400 400<t<650< td=""></t<650<></t<400

Table 1. ΔE and σ_0 in different temperature regions

An approximate order of the values of effective carrier concentration (n) and mobility (μ) could be obtained from the relations :

$$\theta \approx \frac{k}{e} \log_{e} \frac{N_{0}}{n}$$
 (Jonker et al. 1961, Gardner 1963)

and $\sigma = ne\mu$ where N_0 is the number of available states. At 300°K the values of *n* and μ are given in Table 2.

Crystal samples	Fresh	(a)	Heat treated (b)		
	n per c.c. µ	ι cm ² v ^{−1} sec ^{−1}	n per c.c.	$\mu \text{ cm}^2 \text{ v}^{-1} \text{ sec}^{-1}$	
1) In plane	3.9×10 ²⁰	2.5×10-2	2 ×10 ²¹	7.8×10-5	
2) ,,	2×10^{21}	$5.6 imes10^{-3}$	5 ×10 ² 0	5×10^{-4}	
3) Along c-axis	1.4×10^{21}	1.4×10 ⁻³	$9.3 imes 10^{20}$	3.7×10-5	
5) ,,	$1.1 imes 10^{22}$	3 × 10 ⁻⁴	1.2×10^{22}	$7.8 imes 10^{-6}$	
4 8		1000/7			
		5	7.5	10	
	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	A A A A A A A A A A A A A A A A A A A	24 10 48 0 0	d d	

Table 2. n and μ at 300°K

Figure 1. The conductivity of Hematite. 1 and 2 are along the basal plane, 3 and 4 along the c-axis and (a) and (b) are the fresh and heat treated samples.

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Figure 2. The Seebeck effect of Hematite, magnitude only. 1 and 2 are along the basal plane, 3 and 4 along the c-axis and (a) and (b) are the fresh and heat treated samples.

The behaviour of σ and θ between 600°K and 1000°K (figures 1 and 2) is perhaps due to change from impurity region to intrinsic region, and the permanent change in the values of σ and θ due to heat treatment during the first cycle of measurement is most probably due to the impurities and imperfections present in the natural crystals. ΔE in the intrinsic region is about 1 o.v.

The major impurity Ti is perhaps responsible for the donor centres (Morin 1951, Jonker *et al* 1961), which is again very possibly the source of weak ferromagnetism in it below Morin transition (Mukerjee 1967a).

A study of the values of n and μ and that of chemical analysis however suggest the presence of other types of carriers in it.

From figures 1 and 2 it is observed that there is a conspicuous change in θ at about 250°K, and that also there is a change in the value of ΔE within the tomperature range 200°K to 300°K. From earlier observations (Morin 1950, also see Mukerjee 1967b) with purer samples of hematite it has been observed that there is a transition in the magnetic properties at 250°K.

Detailed investigations of these properties on other samples of hematite are in progress and the results will be published soon.

Letters to the Editor

The author is thankful to Shri A. K. Dutta for guidance and to Prof. A. Bose for his kind interest in the work. He also wishes to thank Dr. G. F. Claringbull, Keeper, Natural History Museum, London for kindly presenting the natural crystal of hematite.

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